
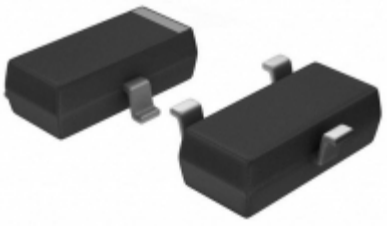
	<p>SI2337DS-T1-E3</p>
	<p>Hersteller-Teilenummer: SI2337DS-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET P-CH 80V 2.2A SOT23-3</p> <p>Datenblätter:  SI2337DS-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 24147 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2337DS-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 80V 2.2A SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	24147 pcs Stock
Hersteller Standard Vorlaufzeit	33 Weeks
detaillierte Beschreibung	P-Channel 80V 2.2A (Tc) 760mW (Ta), 2.5W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-50°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	760mW (Ta), 2.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.2A (Tc)
Rds On (Max) @ Id, Vgs	270 mOhm @ 1.2A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	500pF @ 40V
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2337DS-T1-E3TR







































SI2337DS-T1-E3 ist neu im Original, Suche SI2337DS-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2337DS-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2337DS-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2338DS VISHAY VISHAY SOT-23</p>	 <p>SI2337DS-T1-E3 Vishay / Siliconix MOSFET P-CH 80V 2.2A SOT23-3</p>	 <p>SI2336DS-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 5.2A SOT-23</p>	 <p>SI2338DS-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 6A SOT23</p>
 <p>SI2338DS-T1-E3 VISHAY SI2338DS-T1-E3 VISHAY</p>	 <p>SI2337DS-T1-GE3 Vishay / Siliconix MOSFET P-CH 80V 2.2A SOT23-3</p>	 <p>SI2337DS VISHAY SI2337DS VISHAY</p>	 <p>SI2337DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 80V 2.2A SOT23-3</p>

heiße Teile

Mehr

 SI2333CDS	 SI2333CDS-T1-E3	 SI2333CDS-T1-E3	 SI2333CDS-T1-GE3	 SI2333CDS-T1-GE3
 SI2333DDS-T1-E3	 SI2333DDS-T1-GE3	 SI2333DDS-T1-GE3	 SI2333DS	 SI2333DS-T1-E3
 SI2333DS-T1-E3	 SI2333DS-T1-GE3	 SI2333DS-T1-GE3	 SI2334DS-T1-E3	 SI2334DS-T1-GE3
 SI2334DS-T1-GE3	 SI2335DS-T1	 SI2335DS-T1-E3	 SI2335DS-T1-E3	 SI2335DS-T1-GE3
 SI2335DS-T1-GE3	 SI2336DS-T1-E3	 SI2336DS-T1-GE3	 SI2336DS-T1-GE3	 SI2337DS
 SI2337DS-T1-E3	 SI2337DS-T1-GE3	 SI2337DS-T1-GE3	 SI2338DS-T1-E3	 SI2338DS-T1-GE3
 SI2338DS-T1-GE3	 SI2341DS	 SI2341DS-T1-E3	 SI2341DS-T1-E3	 SI2341DS-T1-GE3
 SI2341DS-T1-GE3	 SI2342DS-T1-E3	 SI2342DS-T1-GE3	 SI2342DS-T1-GE3	 SI2343ADS-T1-GE3
 SI2343CDS	 SI2343CDS-T1-E3	 SI2343CDS-T1-GE3	 SI2343CDS-T1-GE3	 SI2343DS-T1-E3
 SI2343DS-T1-E3	 SI2343DS-T1-GE3	 SI2343DS-T1-GE3	 SI2344DS-E3	 SI2347DS-T1-GE3

Contact us: Info@Y-IC.com

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